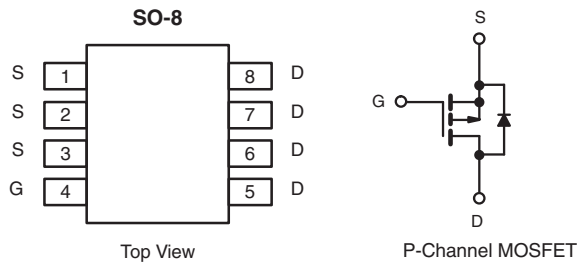


Automotive P-Channel 30 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY | |
|---|--------|
| V_{DS} (V) | - 30 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = - 10$ V | 0.030 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = - 4.5$ V | 0.052 |
| I_D (A) | - 10.8 |
| Configuration | Single |

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 Qualified^c
- Find out more about Vishay's Automotive Grade Product Requirements at: www.vishay.com/applications



| ORDERING INFORMATION | |
|---------------------------------|-----------------|
| Package | SO-8 |
| Lead (Pb)-free and Halogen-free | SQ4431EY-T1-GE3 |

| ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted) | | | | |
|---|----------------|----------------|---------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | | V_{DS} | - 30 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current | $T_C = 25$ °C | I_D | - 10.8 | A |
| | $T_C = 125$ °C | | - 6.2 | |
| Continuous Source Current (Diode Conduction) | | I_S | - 5.4 | |
| Pulsed Drain Current ^a | | I_{DM} | - 43.2 | |
| Single Pulse Avalanche Current | L = 0.1 mH | I_{AS} | - 21 | |
| Single Pulse Avalanche Energy | | E_{AS} | 22 | mJ |
| Maximum Power Dissipation ^a | $T_C = 25$ °C | P_D | 6 | W |
| | $T_C = 125$ °C | | 2 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | - 55 to + 175 | °C |

| THERMAL RESISTANCE RATINGS | | | | |
|----------------------------|------------------------|------------|-------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | PCB Mount ^b | R_{thJA} | 92 | °C/W |
| Junction-to-Foot (Drain) | | R_{thJF} | 25 | |

Notes

- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR-4 material).
- Parametric verification ongoing.

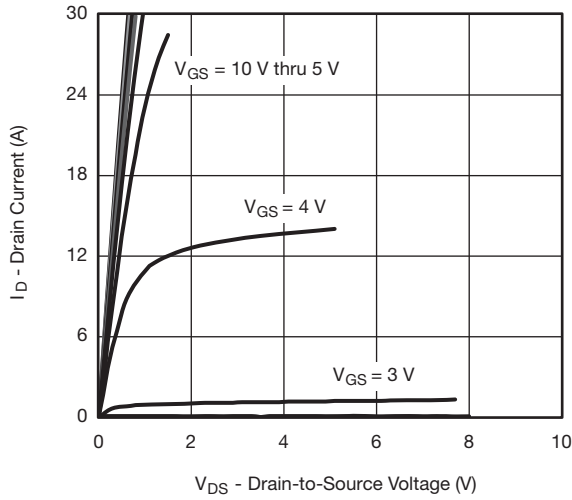
| SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | | |
|---|--------------|--|---|------|-----------|-------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT | |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$ | -30 | - | - | V | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$ | -1.5 | - | -2.5 | | |
| Gate-Source Leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$ | - | - | ± 100 | nA | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = -30\text{ V}$ | - | - | -1.0 | μA |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = -30\text{ V}$, $T_J = 125\text{ }^\circ\text{C}$ | - | - | -50 | |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = -30\text{ V}$, $T_J = 175\text{ }^\circ\text{C}$ | - | - | -150 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{GS} = -10\text{ V}$ | $V_{DS} \leq -5\text{ V}$ | -20 | - | A | |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = -4.5\text{ V}$ | $I_D = -5\text{ A}$ | - | 0.039 | 0.052 | Ω |
| | | $V_{GS} = -10\text{ V}$ | $I_D = -6\text{ A}$ | - | 0.020 | 0.030 | |
| | | $V_{GS} = -10\text{ V}$ | $I_D = -6\text{ A}$, $T_J = 125\text{ }^\circ\text{C}$ | - | 0.029 | 0.044 | |
| | | $V_{GS} = -10\text{ V}$ | $I_D = -6\text{ A}$, $T_J = 175\text{ }^\circ\text{C}$ | - | 0.034 | 0.051 | |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = -15\text{ V}$, $I_D = -6\text{ A}$ | | - | 15 | S | |
| Dynamic^b | | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0\text{ V}$ | $V_{DS} = -25\text{ V}$, $f = 1\text{ MHz}$ | - | 970 | 1210 | pF |
| Output Capacitance | C_{oss} | | | - | 200 | 250 | |
| Reverse Transfer Capacitance | C_{rss} | | | - | 140 | 175 | |
| Total Gate Charge ^c | Q_g | $V_{GS} = -10\text{ V}$ | $V_{DS} = -30\text{ V}$, $I_D = -7.2\text{ A}$ | - | 25 | 38 | nC |
| Gate-Source Charge ^c | Q_{gs} | | | - | 4 | 6 | |
| Gate-Drain Charge ^c | Q_{gd} | | | - | 5 | 8 | |
| Turn-On Delay Time ^c | $t_{d(on)}$ | $V_{DD} = -15\text{ V}$, $R_L = 15\text{ }\Omega$ $I_D \cong -1\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_g = 6\text{ }\Omega$ | | - | 10 | 15 | ns |
| Rise Time ^c | t_r | | | - | 12 | 18 | |
| Turn-Off Delay Time ^c | $t_{d(off)}$ | | | - | 33 | 51 | |
| Fall Time ^c | t_f | | | - | 15 | 23 | |
| Source-Drain Diode Ratings and Characteristics^b | | | | | | | |
| Pulsed Current ^a | I_{SM} | | | - | - | -43.2 | A |
| Forward Voltage | V_{SD} | $I_F = -2.1\text{ A}$, $V_{GS} = 0\text{ V}$ | | - | -0.8 | -1.1 | V |

Notes

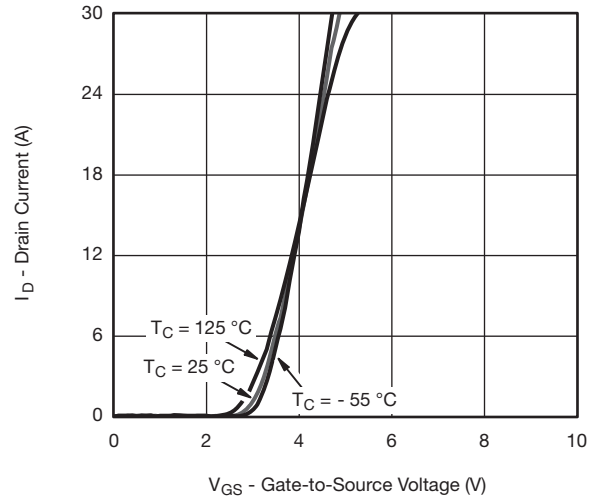
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
 b. Guaranteed by design, not subject to production testing.
 c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

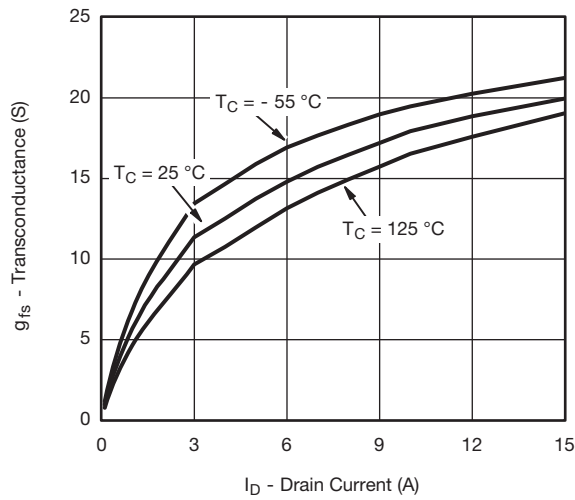
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



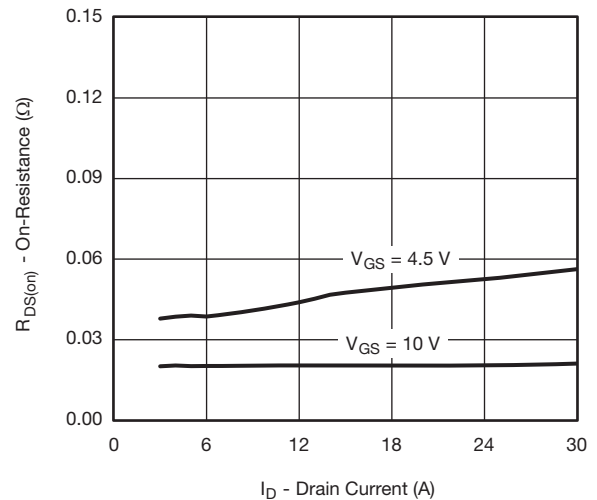
Output Characteristics



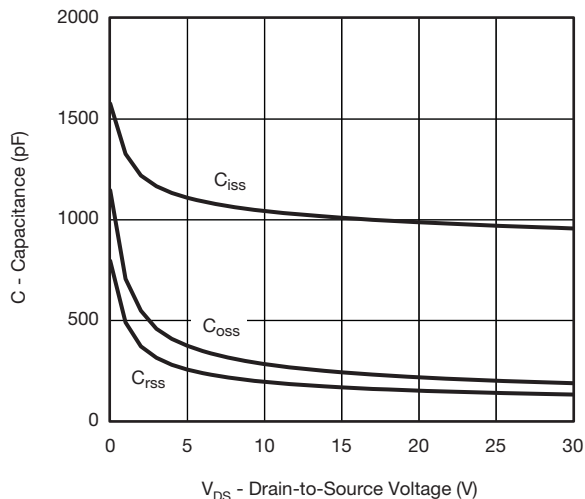
Transfer Characteristics



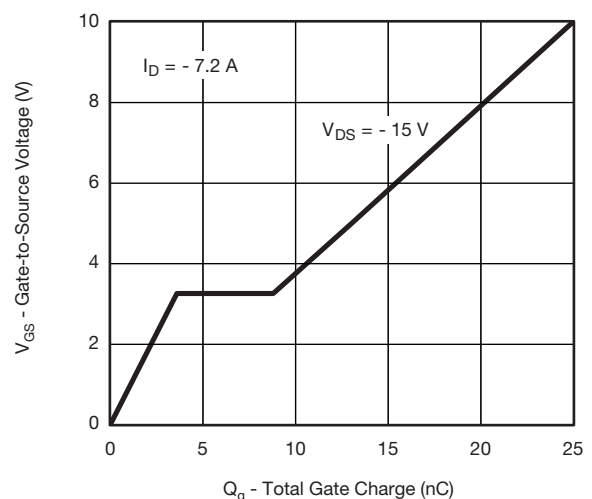
Transconductance



On-Resistance vs. Drain Current

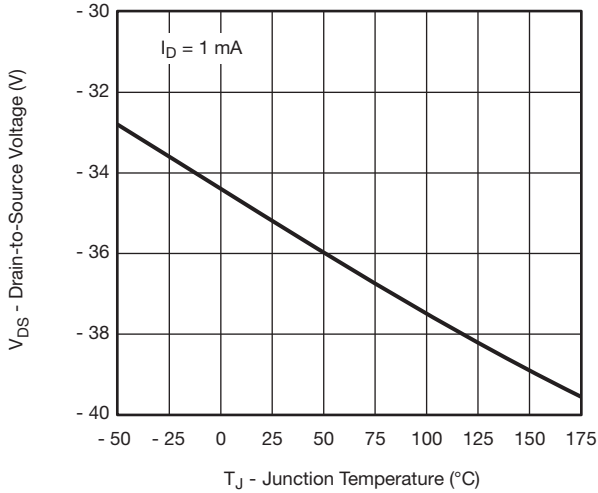


Capacitance

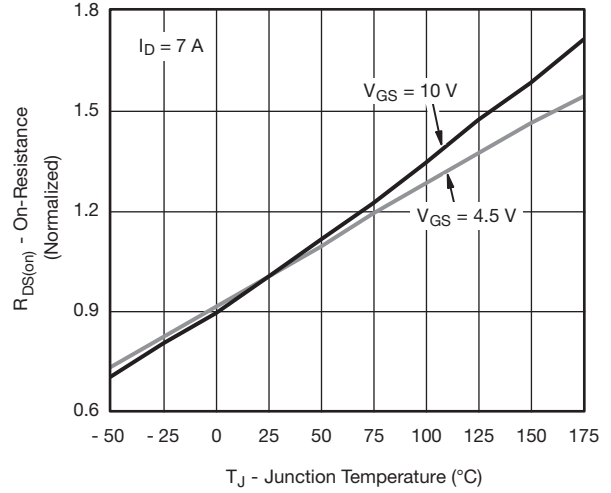


Gate Charge

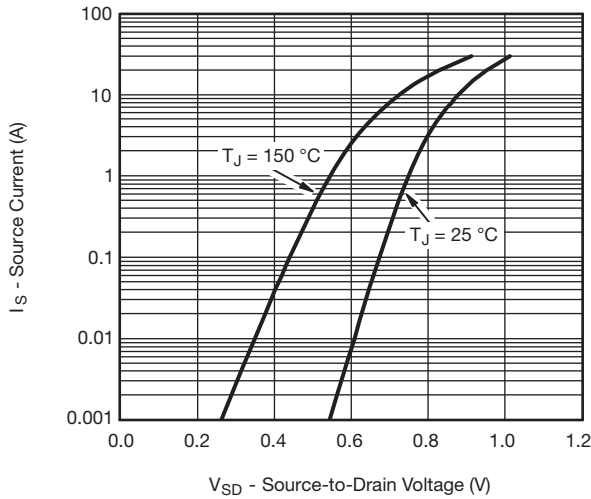
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



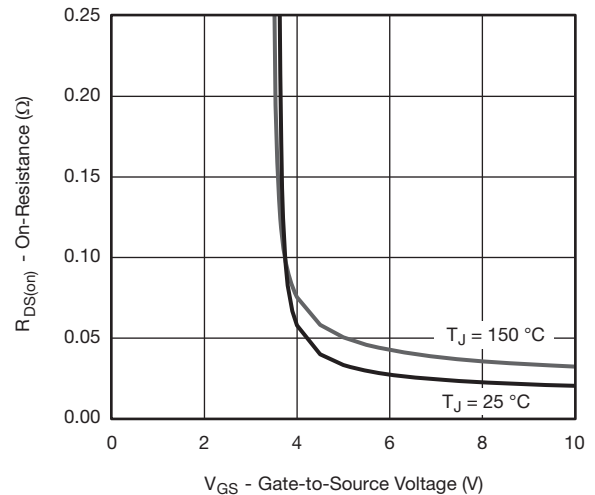
On-Resistance vs. Junction Temperature



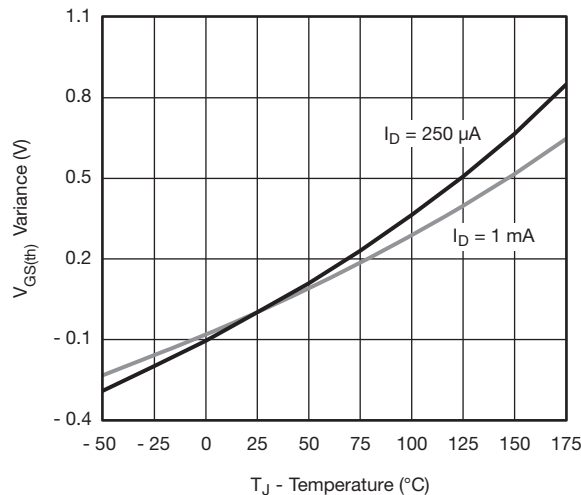
On-Resistance vs. Junction Temperature



Source Drain Diode Forward Voltage

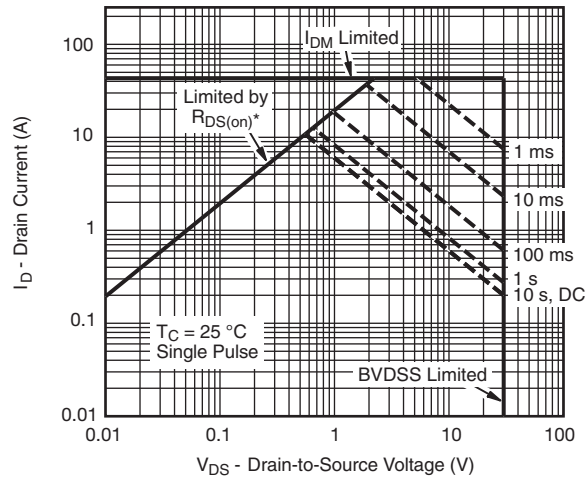


On-Resistance vs. Gate-to-Source Voltage



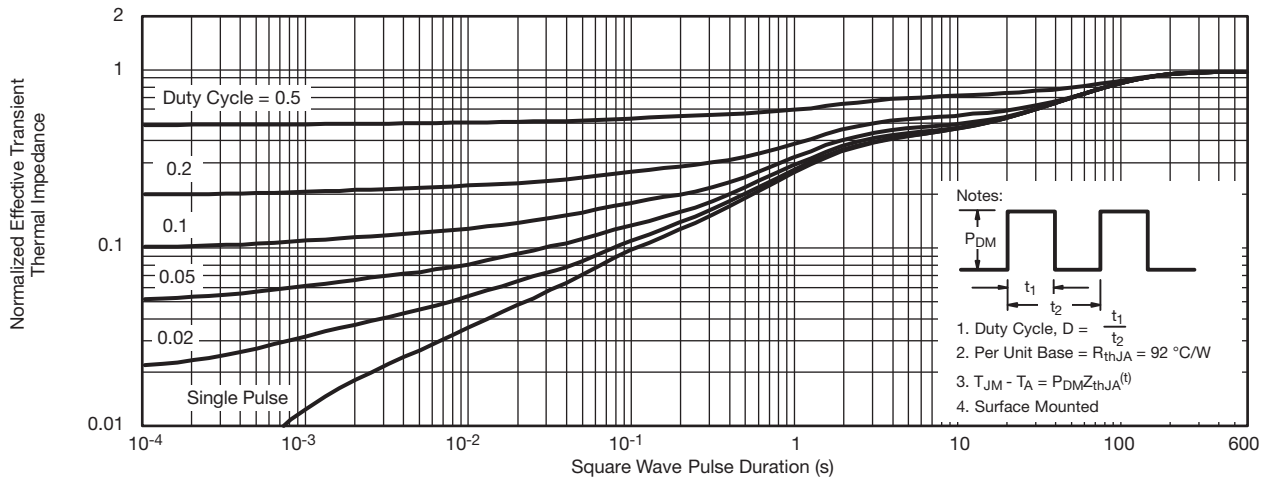
Threshold Voltage

THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



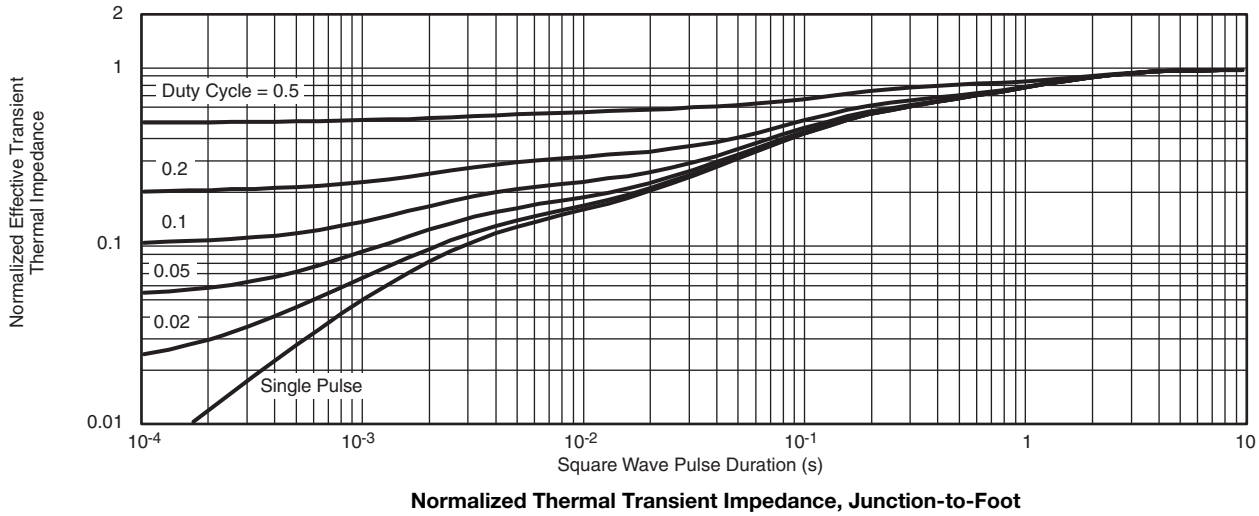
* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^\circ\text{C}$)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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